

Section 16 Recombination & Generation

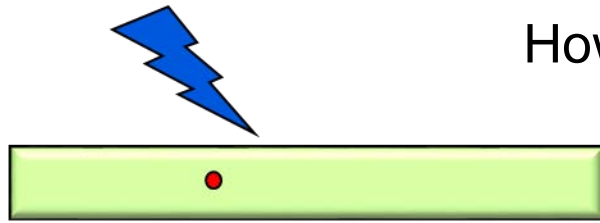
16.7 Surface recombination in depletion region

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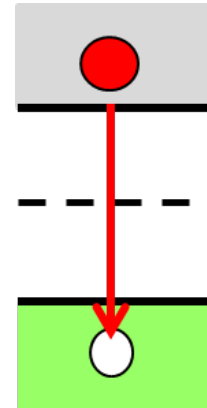


School of Electrical and
Computer Engineering

Section 16 Recombination & Generation



How does the system go BACK to equilibrium?



$$\tau_n = \frac{1}{c_n N_T} \quad \tau_p = \frac{1}{c_p N_T}$$

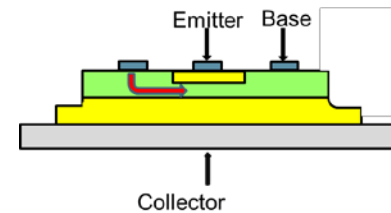
$$n_1 = n_i g_D e^{\beta(E_T - E_i)}$$

$$p_1 = n_i g_D^{-1} e^{\beta(E_i - E_T)}$$

- 16.1 Capture coefficient & Capture Cross Section
- 16.2 Derivation of SRH formula (Shockley, Reed, Hall)
 - » 16.2.1 Trap Assisted Recombination Rates
 - » 16.2.2 Capture and emission relationship (n_1 and p_1)
 - » 16.2.3 Steady State Trap Population
 - » 16.2.4 Recombination-Generation Rate
- 16.3 Application of SRH formula for special cases
 - » Low level, high-level injection, depletion region
- 16.4 Direct and Auger recombination
- 16.5 Nature of interface states
- 16.6 SRH formula adapted to interface states
- 16.7 Surface recombination in depletion region

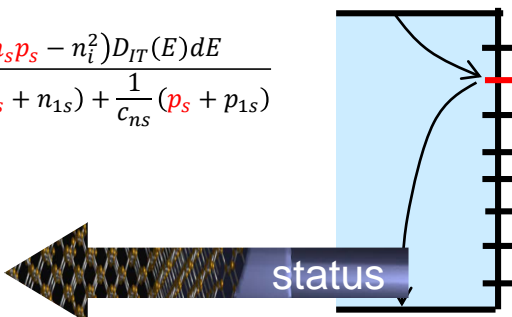
$$R = \frac{pn - n_i^2}{\tau_p(n + n_1) + \tau_n(p + p_1)}$$

$$R = \frac{\Delta n}{\tau_n}$$



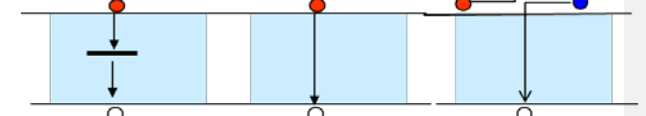
$$R = \frac{\Delta n}{(\tau_n + \tau_p)}$$

$$R(E) = \frac{(n_s p_s - n_i^2) D_{IT}(E) dE}{\frac{1}{c_{ps}}(n_s + n_{1s}) + \frac{1}{c_{ns}}(p_s + p_{1s})}$$



$$R \approx \int_{E_{F'}}^{E_F} c_{ps} \Delta p_{s0} D_{IT}(E) dE$$

$$R = s_g \Delta p_{s0}$$



Vid

Video

Case 2: Recombination in Depletion

$$R(E) = \frac{(n_s p_s - n_i^2) D_{IT}(E) dE}{\frac{1}{c_{ps}} (n_s + n_{1s}) + \frac{1}{c_{ns}} (p_s + p_{1s})}$$

Depletion
=> No free carriers

$$R(E) = \frac{(-n_i^2) D_{IT}(E) dE}{\frac{1}{c_{ps}} (n_{1s}) + \frac{1}{c_{ns}} (p_{1s})}$$

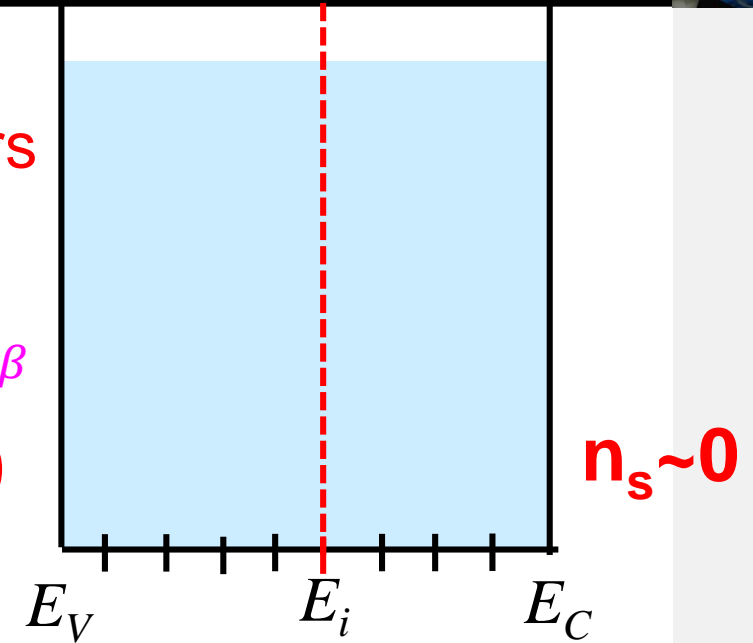
$$n_{1s} = n_i e^{(E-E_i)\beta}$$

$$p_{1s} = n_i e^{-(E-E_i)\beta}$$

$p_s \sim 0$

$$R(E) = \frac{c_{ps} (-n_i^2) D_{IT}(E) dE}{n_i e^{(E-E_i)\beta} + \frac{c_{ps}}{c_{ns}} n_i e^{-(E-E_i)\beta}}$$

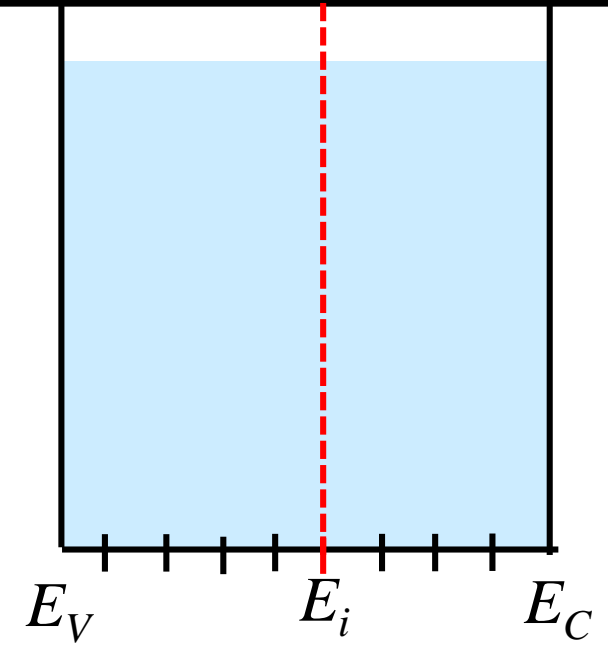
$$R(E) = - \frac{c_{ps} n_i D_{IT}(E) dE}{e^{(E-E_i)\beta} + \frac{c_{ps}}{c_{ns}} e^{(E_i-E)\beta}}$$



Case 2: Recombination in Depletion

$$R(E) = - \frac{c_{ps} n_i D_{IT}(E) dE}{e^{(E - E_i)\beta} + \frac{c_{ps}}{c_{ns}} e^{(E_i - E)\beta}}$$

$$W(E) = 1 + e^{(E - E_F)\beta} + \frac{c_{ps}}{c_{ns}} e^{(E_F - E)\beta}$$

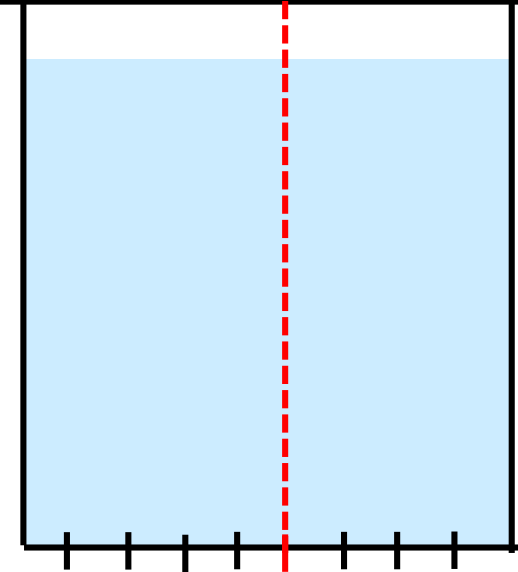


Case 2: Recombination in Depletion

$$R(E) = \frac{c_{ps}n_i D_{IT}(E) dE}{e^{(E-E_i)\beta} + \frac{c_{ps}}{c_{ns}} e^{(E_i-E)\beta}}$$

$$R(E_i) = \frac{A(E)}{e^x + ae^{-x}} dE$$

$x(E) \equiv \beta(E - E_i)$
 $a = \frac{c_{ps}}{c_{ns}}$
 $A(E) = c_{ps}n_i D_{IT}(E)$
 $f(x) = \frac{1}{e^x + ae^{-x}}$

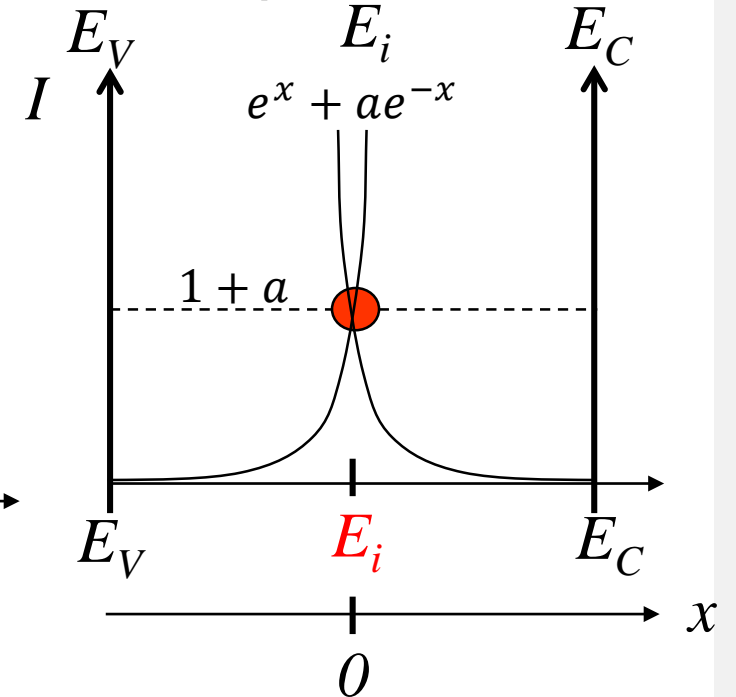
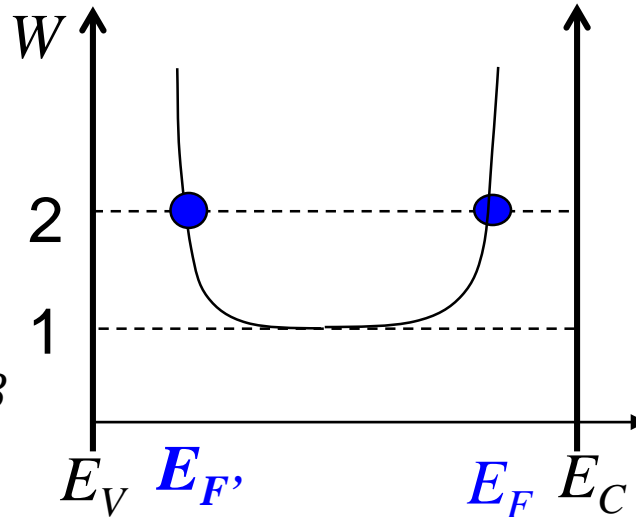


Case 1: Minority Carrier Recombination

$$R(E) = \frac{c_{ps}\Delta p_{s0} D_{IT}(E) dE}{W(E)}$$

$$W(E) = 1 + e^{(E-E_F)\beta} + \frac{c_{ps}}{c_{ns}} e^{(E_F-E)\beta}$$

$$W(E) = 1 + e^x + ae^{-x}$$



Case 2: Recombination in Depletion

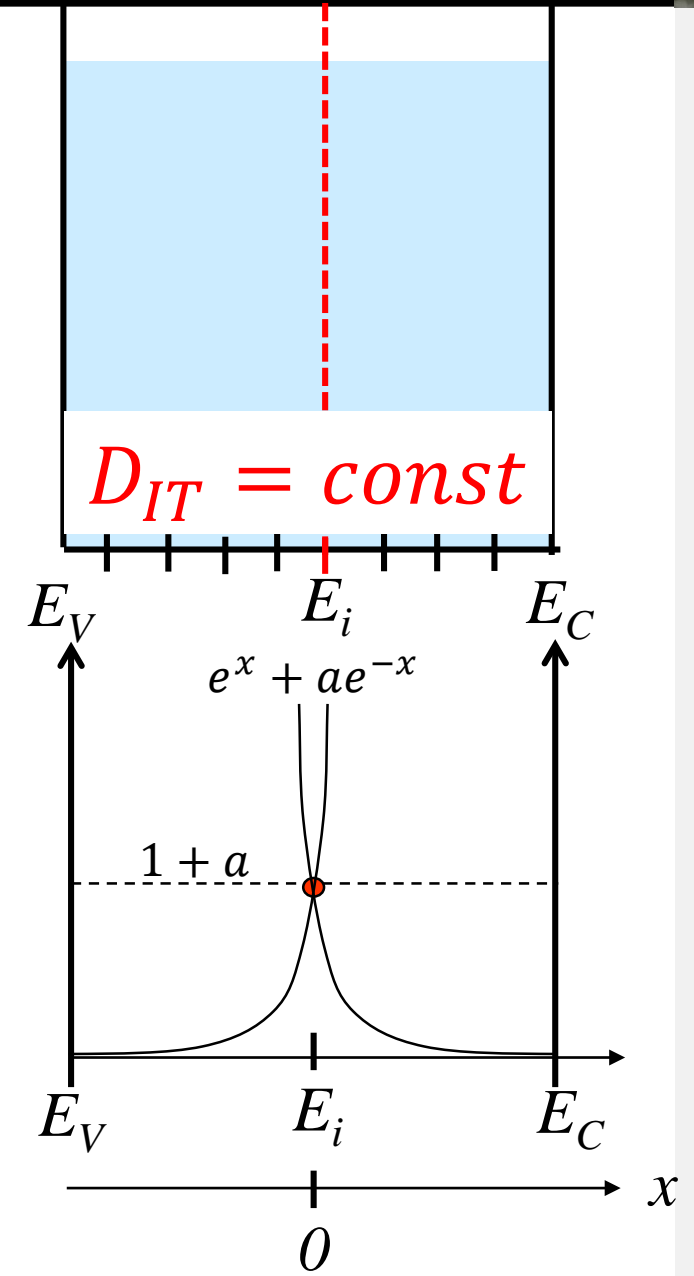
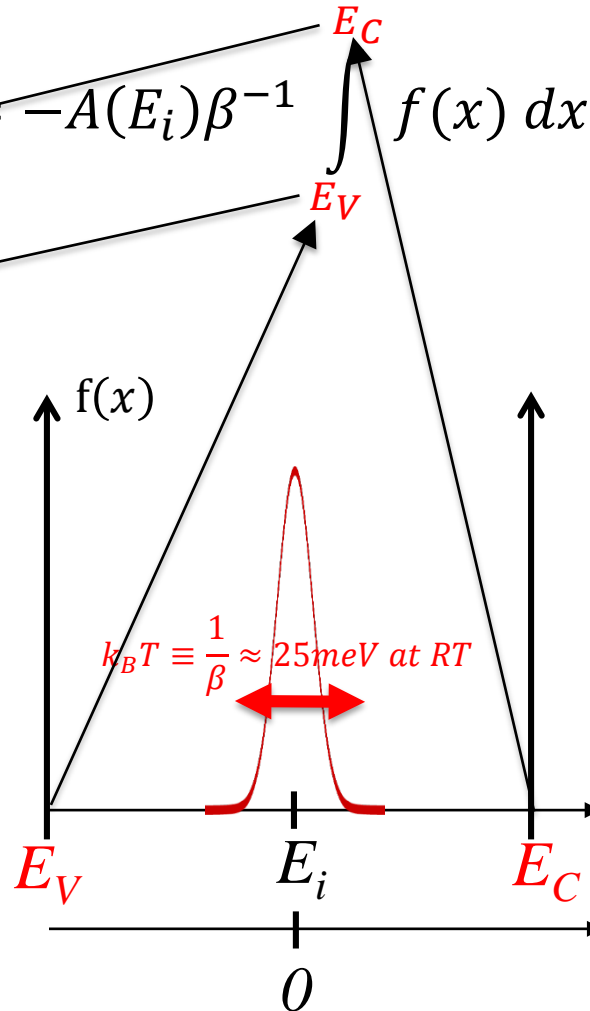
$$R(E) = -\frac{A(E)}{e^x + ae^{-x}} dE \quad A(E) = c_{ps} n_i D_{IT}(E) \quad f(x) = \frac{1}{e^x + ae^{-x}}$$

$$x(E) \equiv \beta(E - E_i) \quad a = \frac{c_{ps}}{c_{ns}}$$

$$A(E) \approx A(E_i) = c_{ps} n_i D_{IT}(E_i)$$

$$R = \int_{E_V}^{E_C} R(E) dE = -A(E_i) \int_{E_V}^{E_C} f(x) \frac{dx}{dE} dE = -A(E_i) \beta^{-1} \int_{E_V}^{E_C} f(x) dx$$

$$R \approx A(E_i) \beta^{-1} \int_{-\infty}^{\infty} f(x) dx$$



Case 2: Recombination in Depletion

$$R(E) = -\frac{A(E)}{e^x + ae^{-x}} dE \quad A(E) = c_{ps} n_i D_{IT}(E)$$

$$x(E) \equiv \beta(E - E_i)$$

$$A(E) \approx A(E_i) = c_{ps} n_i D_{IT}(E_i)$$

$$a = \frac{c_{ps}}{c_{ns}}$$

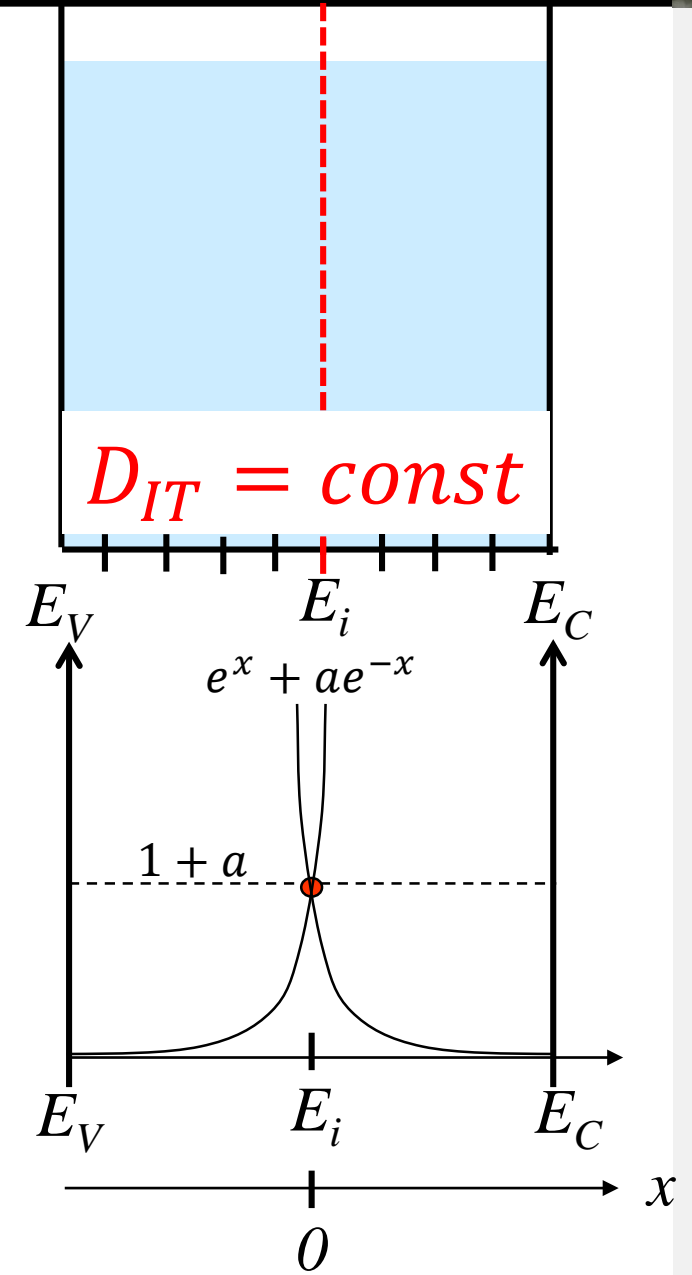
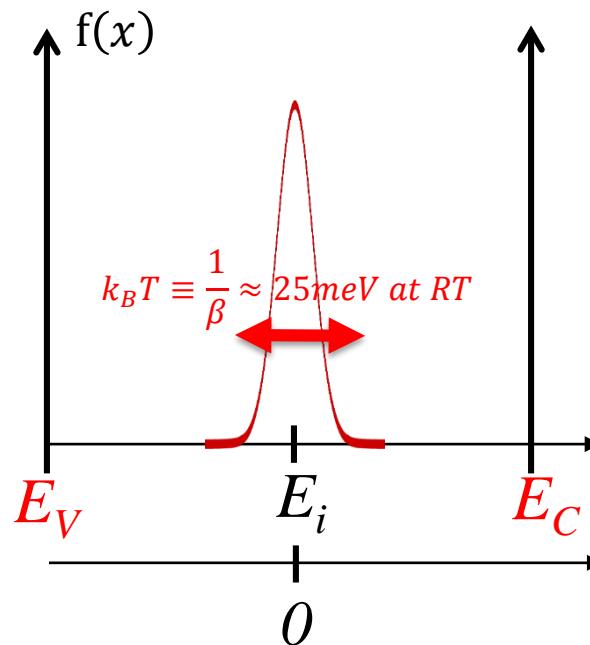
$$R = \int_{E_V}^{E_C} R(E) dE = -A(E_i) \int_{E_V}^{E_C} f(x) \frac{dx}{dE} dE = -A(E_i) \beta^{-1} \int_{E_V}^{E_C} f(x) dx$$

$$R \approx A(E_i) \beta^{-1} \int_{-\infty}^{\infty} f(x) dx$$

$$f(x) = \frac{1}{e^x + ae^{-x}}$$

$$F(x) = \int f(x) dx = \frac{1}{\sqrt{a}} \tan^{-1}(e^x / \sqrt{a}) + C$$

$$I = \int_{-\infty}^{\infty} f(x) dx = \frac{\pi}{2\sqrt{a}}$$



Case 2: Recombination in Depletion

$$R(E) = -\frac{A(E)}{e^x + ae^{-x}} dE$$

$$A(E) = c_{ps} n_i D_{IT}(E)$$

$$f(x) = \frac{1}{e^x + ae^{-x}}$$

$$x(E) \equiv \beta(E - E_i)$$

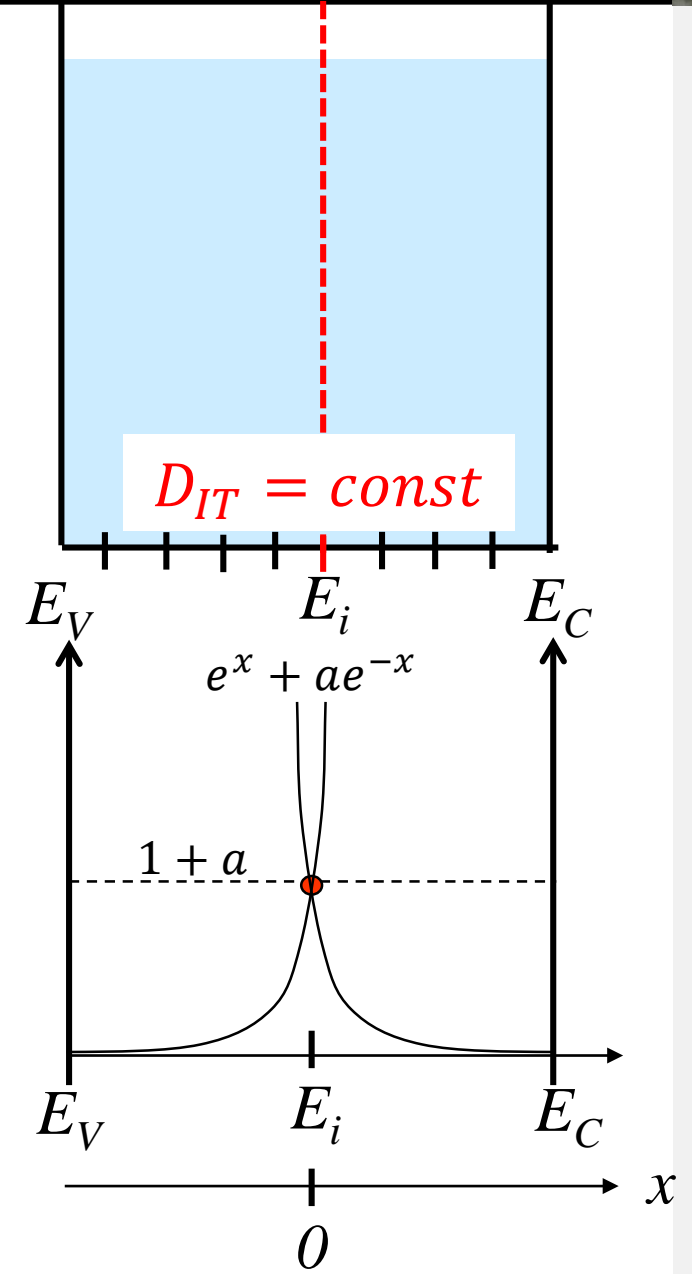
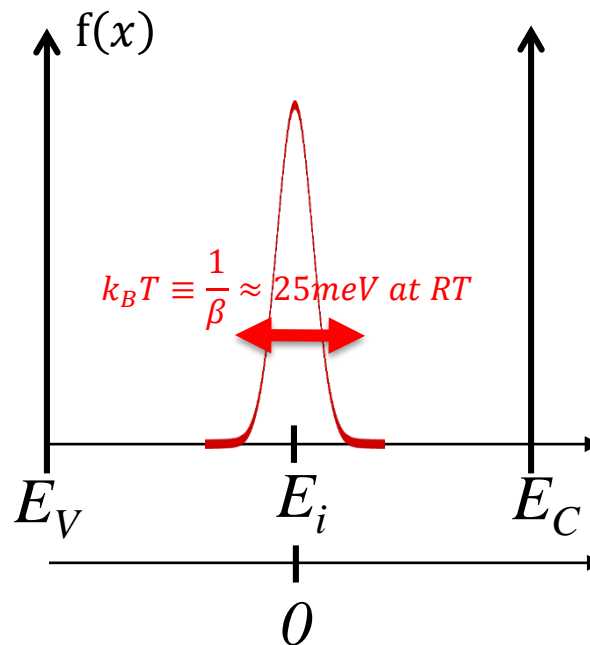
$$A(E) \approx A(E_i) = c_{ps} n_i D_{IT}(E_i)$$

$$a = \frac{c_{ps}}{c_{ns}}$$

$$R = \int_{E_V}^{E_C} R(E) dE = -A(E_i) \int_{E_V}^{E_C} f(x) \frac{dx}{dE} dE = -A(E_i) \beta^{-1} \int_{E_V}^{E_C} f(x) dx$$

$$R \approx -A(E_i) \beta^{-1} \int_{-\infty}^{\infty} f(x) dx = -A(E_i) \beta^{-1} \frac{\pi}{2\sqrt{a}}$$

$$I = \int_{-\infty}^{\infty} f(x) dx = \frac{\pi}{2\sqrt{a}}$$



Case 2: Recombination in Depletion

$$R(E) = -\frac{A(E)}{e^x + ae^{-x}} dE$$

$$A(E) = c_{ps} n_i D_{IT}(E)$$

$$x(E) \equiv \beta(E - E_i)$$

$$f(x) = \frac{1}{e^x + ae^{-x}}$$

$$A(E) \approx A(E_i) = c_{ps} n_i D_{IT}(E_i)$$

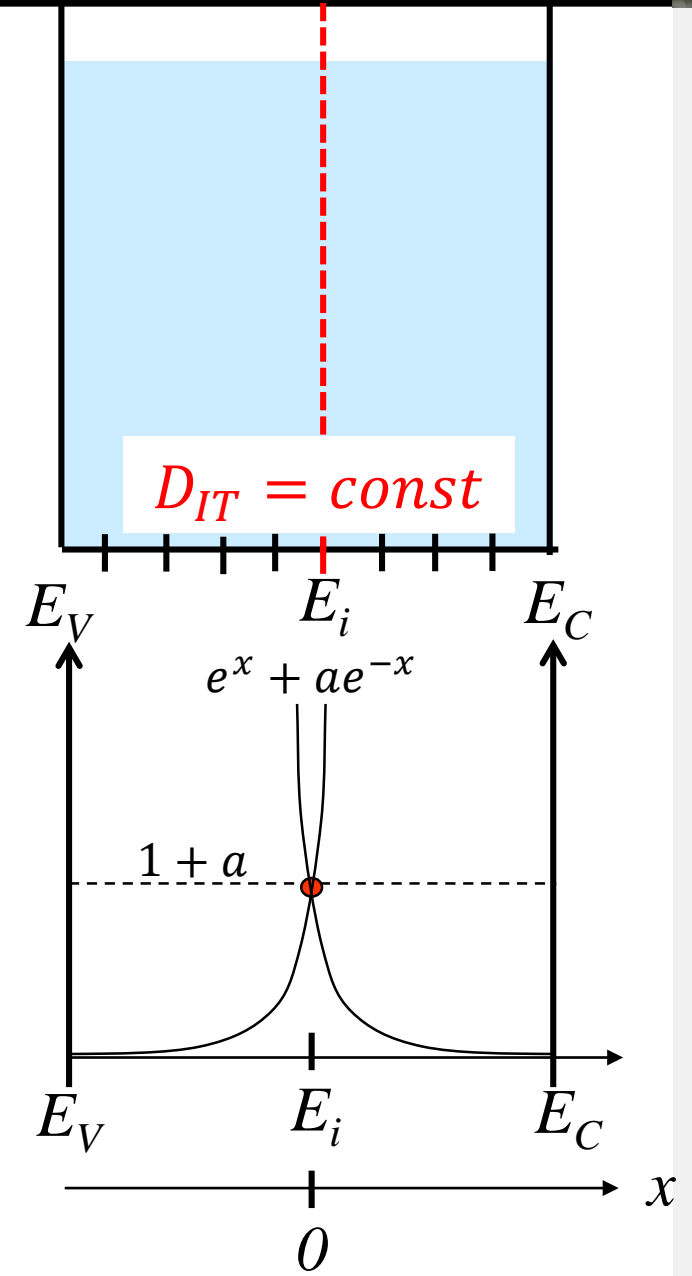
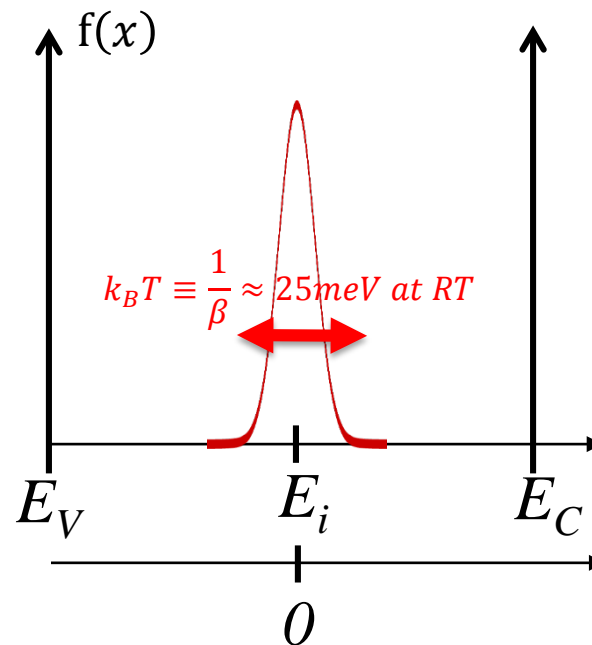
$$a = \frac{c_{ps}}{c_{ns}}$$

$$R = \int_{E_V}^{E_C} R(E) dE$$

$$R \approx -A(E_i) \beta^{-1} \int_{-\infty}^{\infty} f(x) dx = -A(E_i) \beta^{-1} \frac{\pi}{2\sqrt{a}}$$

$$R \approx -c_{ps} n_i D_{IT}(E_i) \beta^{-1} \frac{\pi}{2} \sqrt{c_{ns}/c_{ps}}$$

$$R \approx -\frac{\pi}{2} \sqrt{c_{ps} c_{ns}} k_B T D_{IT} n_i$$

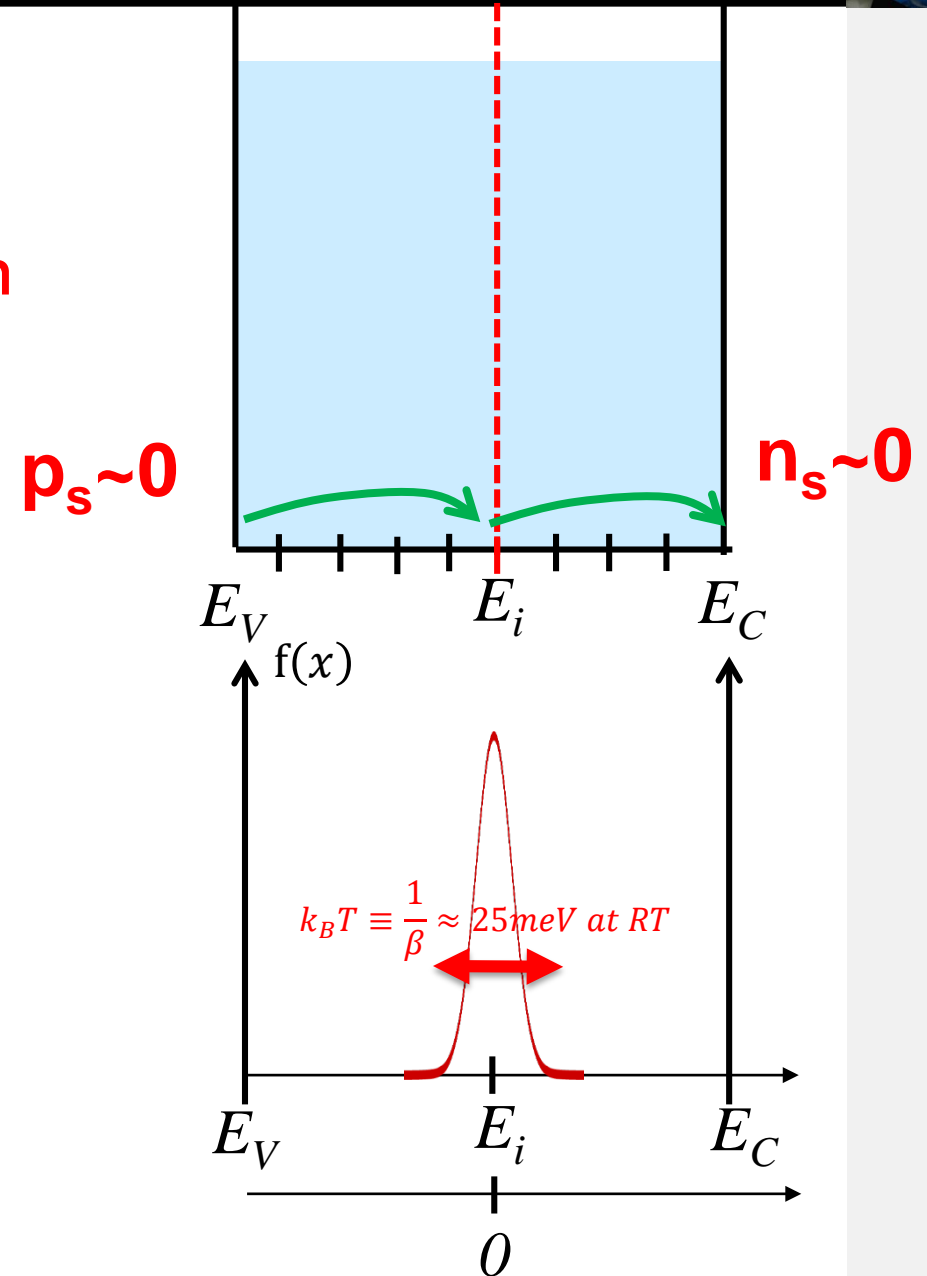


Case 2: Recombination in Depletion

Case 2: Generation in Depletion

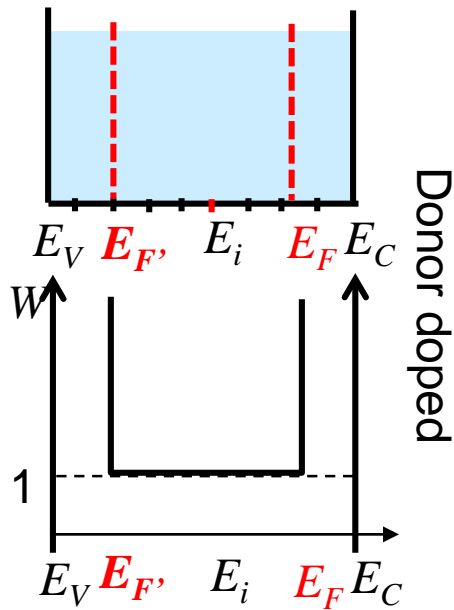
$$R \approx -\frac{\pi}{2} \sqrt{c_{ps}c_{ns}} k_B T D_{IT} n_i$$

$$G \approx \frac{\pi}{2} \sqrt{c_{ps}c_{ns}} k_B T D_{IT} n_i$$



Compare Case 1 and Case 2

Case 1: Minority Carrier Recombination



$$R \approx (E_F - E'_F) c_{ps} D_{IT} \Delta p_{s0}$$

$$R \approx (E_F - E'_F) c_{ns} D_{IT} \Delta n_{s0}$$

$$R_{MC} = A \Delta E \Delta n$$

$$\Delta E = E_F - E_{F'} \approx 1.000 \text{ eV}$$

$$N_A \gg \Delta n \gg n_i$$

$$\Delta n \approx 10^{16} \text{ cm}^{-3}$$

Energy loss through many states & carriers

$$\frac{R_{MC}}{G_D} \approx 10^8$$

Case 2: Generation in Depletion

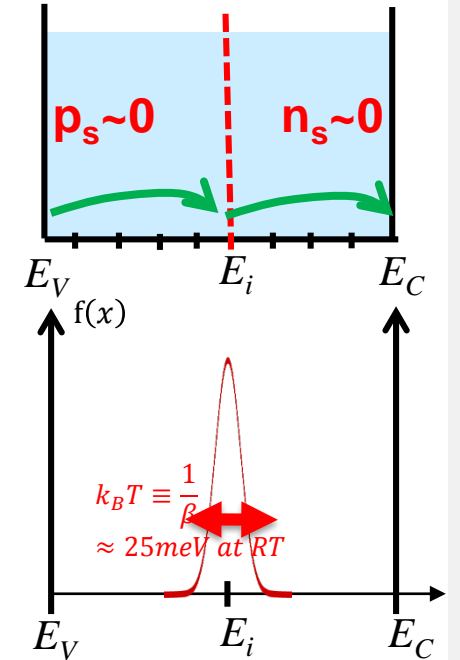
$$R \approx -\frac{\pi}{2} \sqrt{c_{ps} c_{ns}} k_B T D_{IT} n_i$$

$$G \approx \frac{\pi}{2} \sqrt{c_{ps} c_{ns}} k_B T D_{IT} n_i$$

$$G_D \approx \frac{\pi}{2} A \Delta E \Delta n$$

$$\Delta E = k_B T \approx 0.025 \text{ eV}$$

$$\Delta n = n_i \approx 10^{10} \text{ cm}^{-3}$$



Thermal energy gain through few states & carriers

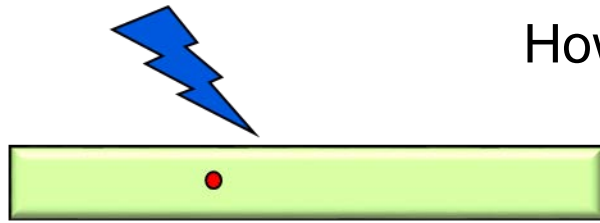
Summary

$$R \approx -\frac{\pi}{2} \sqrt{c_{ps}c_{ns}} k_B T D_{IT} n_i \quad \text{Interface (depletion)}$$

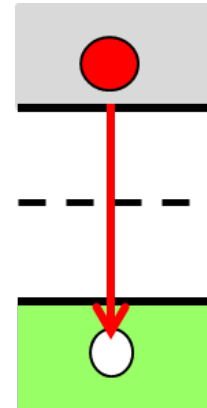
$$R \approx (E_F - E'_F) c_{ps} D_{IT} \Delta p_{s0} \quad \text{Interface (minority)}$$

$$R = c_p N_T \Delta p \quad \text{Bulk (minority)}$$

Section 16 Recombination & Generation



How does the system go BACK to equilibrium?



$$\tau_n = \frac{1}{c_n N_T} \quad \tau_p = \frac{1}{c_p N_T}$$

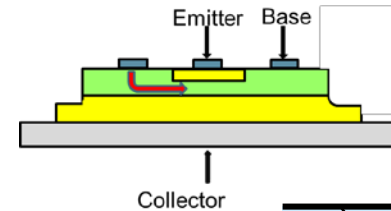
$$n_1 = n_i g_D e^{\beta(E_T - E_i)}$$

$$p_1 = n_i g_D^{-1} e^{\beta(E_i - E_T)}$$

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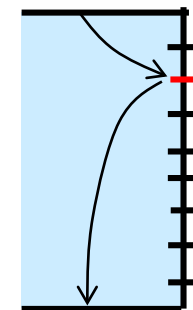
$$R = \frac{pn - n_i^2}{\tau_p(n + n_1) + \tau_n(p + p_1)}$$

$$R = \frac{\Delta n}{\tau_n}$$



$$R = \frac{\Delta n}{(\tau_n + \tau_p)}$$

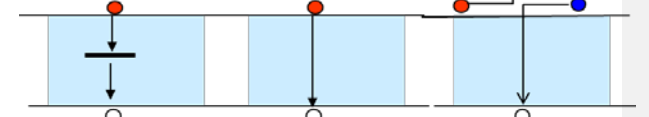
$$R(E) = \frac{(n_s p_s - n_i^2) D_{IT}(E) dE}{\frac{1}{c_{ps}}(n_s + n_{1s}) + \frac{1}{c_{ns}}(p_s + p_{1s})}$$



$$R \approx \int_{E_{F'}}^{E_F} c_{ps} \Delta p_{s0} D_{IT}(E) dE$$

$$R = s_g \Delta p_{s0}$$

$$R \approx -\frac{\pi}{2} \sqrt{c_{ps} c_{ns}} k_B T D_{IT} n_i$$



Vid

Video